



# FUKUCOM COMPANY LTD.

## 福 靈 有 限 公 司

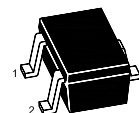
FLAT P, 3/F., EVEREST INDUSTRIAL CENTRE, 396 KWUN TONG ROAD,  
KWUN TONG, KOWLOON, HONG KONG.

TEL: 852-2790 0314 FAX: 852-2790 0206

### MMBT8050W

#### NPN Silicon Epitaxial Planar Transistor

for switching and amplifier applications



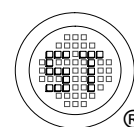
1.Base 2.Emitter 3.Collector  
SOT-323 Plastic Package

#### Absolute Maximum Ratings ( $T_a = 25\text{ }^\circ\text{C}$ )

Parameter	Symbol	Value	Unit
Collector Emitter Voltage	$V_{CEO}$	25	V
Collector Base Voltage	$V_{CBO}$	40	V
Emitter Base Voltage	$V_{EBO}$	6	V
Collector Current	$I_C$	600	mA
Power Dissipation	$P_{tot}$	200	mW
Junction Temperature	$T_j$	150	$^\circ\text{C}$
Storage Temperature Range	$T_s$	- 55 to + 150	$^\circ\text{C}$

#### Characteristics at $T_a = 25\text{ }^\circ\text{C}$

Parameter	Symbol	Min.	Typ.	Max.	Unit
DC Current Gain at $V_{CE} = 1\text{ V}$ , $I_C = 100\text{ mA}$  at $V_{CE} = 1\text{ V}$ , $I_C = 500\text{ mA}$	MMBT8050CW $h_{FE}$	100	-	250	-
	MMBT8050DW $h_{FE}$	160	-	400	-
	$h_{FE}$	40	-	-	-
Collector Cutoff Current at $V_{CB} = 35\text{ V}$	$I_{CBO}$	-	-	100	nA
Collector Saturation Voltage at $I_C = 500\text{ mA}$ , $I_B = 50\text{ mA}$	$V_{CE(sat)}$	-	-	0.5	V
Base Saturation Voltage at $I_C = 500\text{ mA}$ , $I_B = 50\text{ mA}$	$V_{BE(sat)}$	-	-	1.2	V
Collector Emitter Breakdown Voltage at $I_C = 2\text{ mA}$	$V_{(BR)CEO}$	25	-	-	V
Collector Base Breakdown Voltage at $I_C = 10\text{ }\mu\text{A}$	$V_{(BR)CBO}$	40	-	-	V
Emitter Base Breakdown Voltage at $I_E = 100\text{ }\mu\text{A}$	$V_{(BR)EBO}$	6	-	-	V
Gain Bandwidth Product at $V_{CE} = 5\text{ V}$ , $I_C = 10\text{ mA}$ , $f = 50\text{ MHz}$	$f_T$	-	100	-	MHz
Collector Base Capacitance at $V_{CB} = 10\text{ V}$ , $f = 1\text{ MHz}$	$C_{CBO}$	-	12	-	pF



Dated : 11/08/2006



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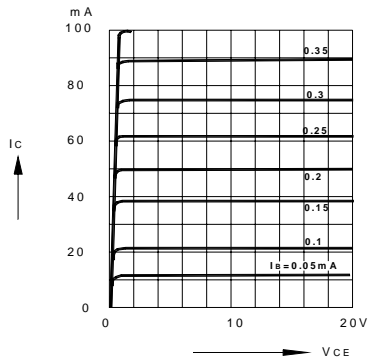
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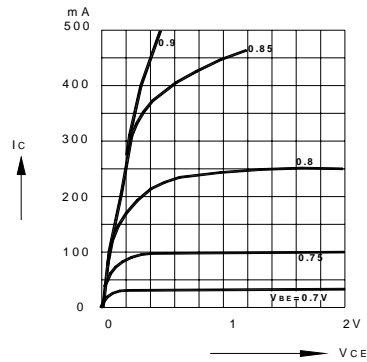
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**MMBT8050W**

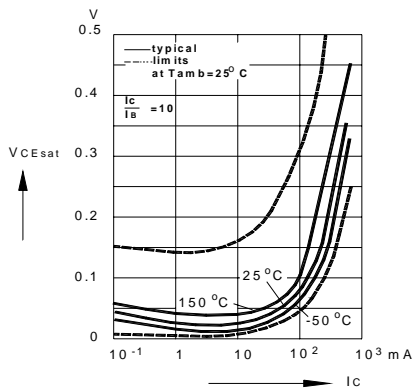
Common emitter collector characteristics



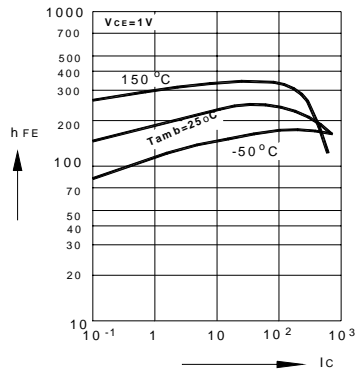
Common emitter collector characteristics



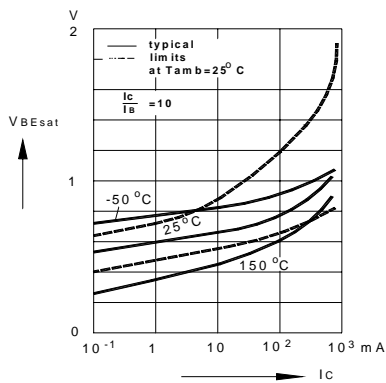
Collector saturation voltage versus collector current



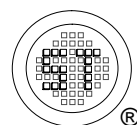
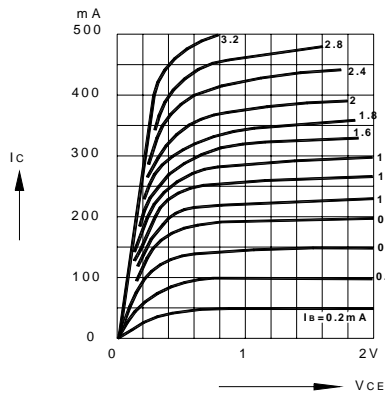
DC current gain versus collector current



Base saturation voltage versus collector current



Common emitter collector characteristics



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